# **BAV23** series

# Dual high-voltage switching diodes Rev. 07 — 19 March 2010

Product data sheet

#### 1. **Product profile**

### 1.1 General description

Dual high-voltage switching diodes, encapsulated in small Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview** 

Type number	Package		Configuration	
	NXP	JEDEC		
BAV23A	SOT23	TO-236AB	dual common anode	
BAV23C	SOT23	TO-236AB	dual common cathode	
BAV23S	SOT23	TO-236AB	dual series	
BAV23	SOT143B	-	dual isolated	

#### 1.2 Features and benefits

- High switching speed: t<sub>rr</sub> ≤ 50 ns
- Low leakage current
- Repetitive peak reverse voltage:  $V_{RRM} \le 250 \text{ V}$
- Low capacitance: C<sub>d</sub> ≤ 2 pF
- Small SMD plastic package

### 1.3 Applications

- High-speed switching at high voltage
- High-voltage general-purpose switching

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I <sub>R</sub>	reverse current	V <sub>R</sub> = 200 V	-	-	100	nA
V <sub>R</sub>	reverse voltage		-	-	200	V
t <sub>rr</sub>	reverse recovery time		<u>[1]</u> -	-	50	ns

<sup>[1]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega$ ; measured at  $I_R$  = 1 mA.



# 2. Pinning information

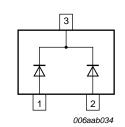
Table 3. Pinning

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Pin	Description	Simplified outline	Graphic symbol
BAV23A			
1	cathode (diode 1)		
2	cathode (diode 2)	3	3
3	common anode	1 2	
			1 2
			006aab099

BAV23C

1	anode (diode 1)
2	anode (diode 2)
3	common cathode

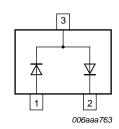




BAV23S

1	anode (diode 1)
2	cathode (diode 2)
3	cathode (diode 1), anode (diode 2)

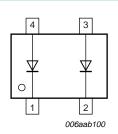




#### **BAV23**

1	cathode (diode 1)
2	cathode (diode 2)
3	anode (diode 2)
4	anode (diode 1)





### 3. Ordering information

Table 4. Ordering information

Type number	Package					
	Name	Description	Version			
BAV23A	<b>'-</b>	plastic surface-mounted package; 3 leads	SOT23			
BAV23C						
BAV23S						
BAV23	-	plastic surface-mounted package; 4 leads	SOT143B			

### 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
BAV23A	*V0
BAV23C	*V9
BAV23S	*V5
BAV23	*L3

<sup>[1] \* = -:</sup> made in Hong Kong

### 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
$V_{RRM}$	repetitive peak reverse voltage		-	250	V
$V_R$	reverse voltage		-	200	V
I <sub>F</sub>	forward current		<u>[1]</u> _	225	mA
			[2] _	125	mA
I <sub>FRM</sub>	repetitive peak forward current		-	625	mA
I <sub>FSM</sub>	non-repetitive peak forward	square wave	[3]		
	current	t <sub>p</sub> = 1 μs	-	9	Α
		$t_p = 100 \ \mu s$	-	3	Α
		$t_p = 10 \text{ ms}$	-	1.7	Α

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

 Table 6.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	<u>[4]</u> _	250	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Single diode loaded.

### 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] _	-	500	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		-	-	360	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

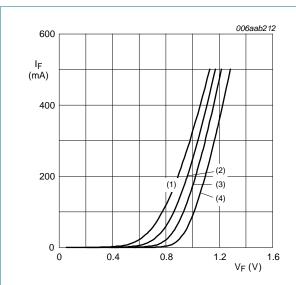
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	Per diode					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 100 mA	-	-	1.0	V
		$I_F = 200 \text{ mA}$	-	-	1.25	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 200 V	-	-	100	nA
		$V_R = 200 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	100	μΑ
$C_d$	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	2	pF
t <sub>rr</sub>	reverse recovery time		<u>[1]</u> _	-	50	ns

<sup>[1]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega;$  measured at  $I_R$  = 1 mA.

<sup>[2]</sup> Double diode loaded.

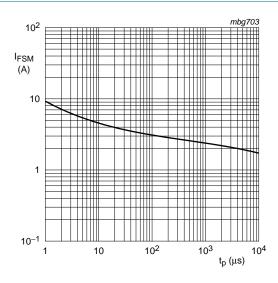
<sup>[3]</sup>  $T_i = 25$  °C prior to surge.

<sup>[4]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$
- (4)  $T_{amb} = -40 \, ^{\circ}C$

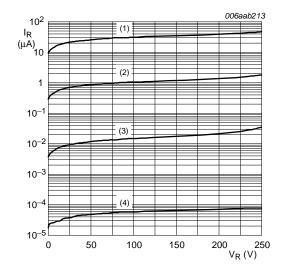
Fig 1. Forward current as a function of forward voltage; typical values



Based on square wave currents.

T<sub>i</sub> = 25 °C; prior to surge

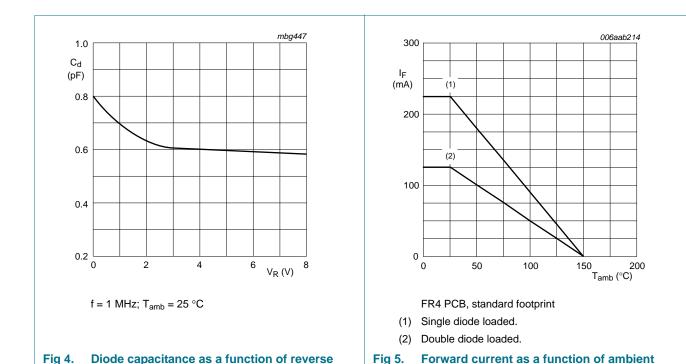
Fig 2. Non-repetitive peak forward current as a function of pulse duration; maximum values



- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$
- (4)  $T_{amb} = -40 \, ^{\circ}C$

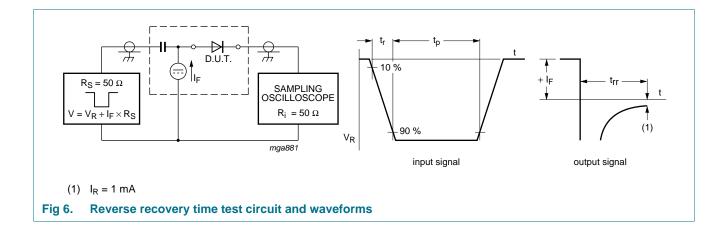
Fig 3. Reverse current as a function of reverse voltage; typical values

temperature; derating curves

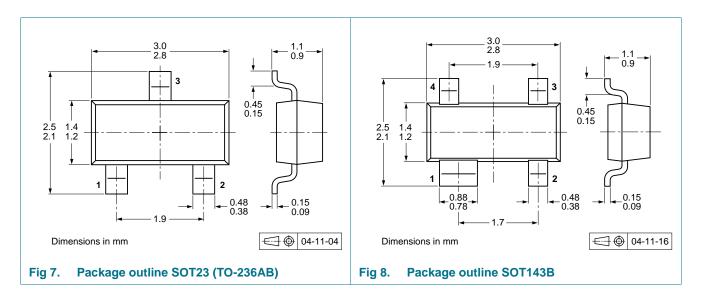


### 8. Test information

voltage; typical values



### 9. Package outline



### 10. Packing information

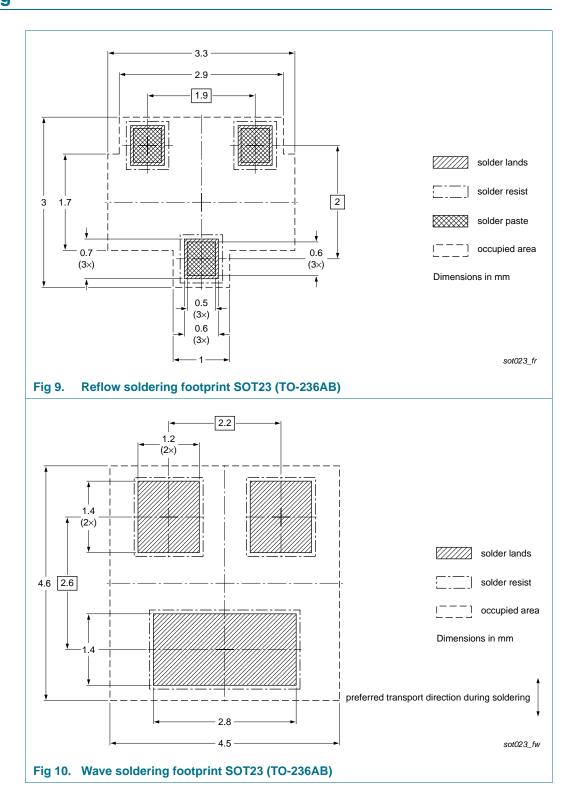
Table 9. Packing methods

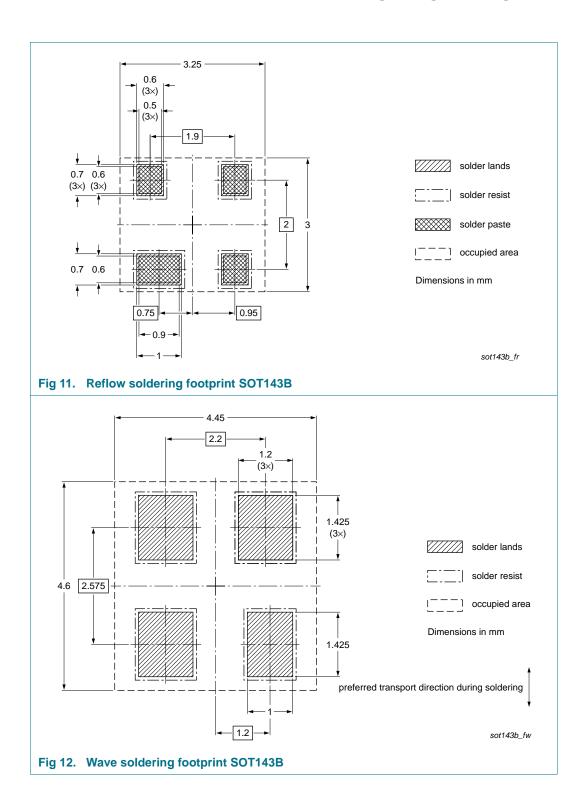
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing 6	Packing quantity	
			3000	10000	
BAV23A	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235	
BAV23C					
BAV23S					
BAV23	SOT143B	4 mm pitch, 8 mm tape and reel	-215	-235	

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

### 11. Soldering





# 12. Revision history

### Table 10. Revision history

	•					
Document ID	Release date	Data sheet status	Change notice	Supersedes		
BAV23_SER_7	20100319	Product data sheet	-	BAV23_SER_6		
Modifications:	<ul> <li>Type numbers BAV23A/DG, BAV23C/DG, BAV23S/DG and BAV23/DG deleted</li> </ul>					
	<ul> <li>Type numbers BAV23A and BAV23C added</li> </ul>					
	<ul> <li><u>Table 5 "Marking codes"</u>: updated</li> </ul>					
	<ul> <li><u>Figure 6</u>: adaptation of test condition to specified characteristics in <u>Table 8</u></li> </ul>					
	• <u>Figure 9, 10, 11</u> and <u>12</u> : updated					
	<ul> <li>Section 13 "Legal information": updated</li> </ul>					
BAV23_SER_6	20080303	Product data sheet	-	BAV23S_5		
				BAV23_2		
BAV23S_5	20011012	Product specification	-	BAV23S_4		
BAV23_2	19960917	Product specification	-	BAV23_1		

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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BAV23\_SER\_7

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# **BAV23** series

### **Dual high-voltage switching diodes**

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